

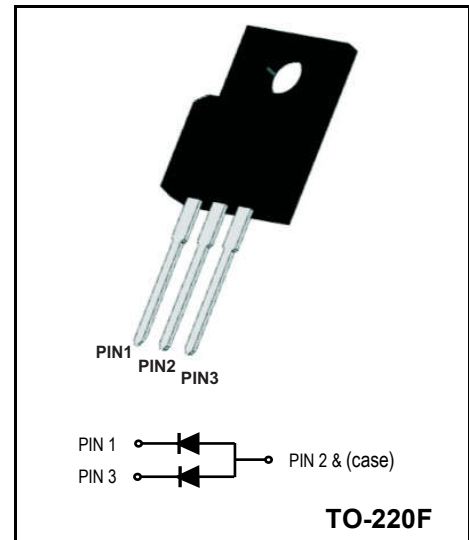
**Fast Recovery Rectifiers**

**Reverse Voltage - 1000V**

**Forward Current - 10A**

**FEATURES**

- Glass passivated chip junctions
- Low reverse current operation
- High Junction Temperature
- Fast recovery time for switching
- High Forward Surge Capability
- Lead free in compliance with EU RoHS 2011/65/EU directive



**MECHANICAL DATA**

- Circuit figure: Common Anode
- Leads: Solderable per mil-std-202, Method 208
- Polarity: as marked
- Mounting torque: 5 in-lbs maximum
- Terminals: Puretin plated
- Weight: TO-220F 1.7 grams

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (TA=25°C)**

RATINGS	SYMBOL	Value	Units
Maximum repetitive reverse voltage	$V_{RRM}$	1000	V
Maximum RMS voltage	$V_{RMS}$	700	V
Maximum DC blocking voltage	$V_{DC}$	1000	V
Maximum average forward current per device per diode	$I_{AV}$	10 5	A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	150	A
Typical thermal resistance per diode (Note 1)	$R_{\theta-JC}$	4.0	°C/W
Operation Junction Temperature and Storage Temperature	$T_J, T_{STG}$	-55 ~ +150	°C
<b>CHARACTERISTICS</b>			
Maximum forward voltage per leg at 5 A	$V_F$	1.3	V
Maximum average reverse current at rated DC blocking voltage $T_J=25^{\circ}C$ $T_J=125^{\circ}C$	$I_R$	10 250	$\mu A$
Maximum reverse recovery time (Note 2)	$T_{RR}$	500	nS

Notes: 1. Thermal resistance from junction to case.  
2. Test conditions:  $I_F=0.5A, I_R=1.0A, I_{RR}=0.25A.$

**Ratings And Characteristic Curves**

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

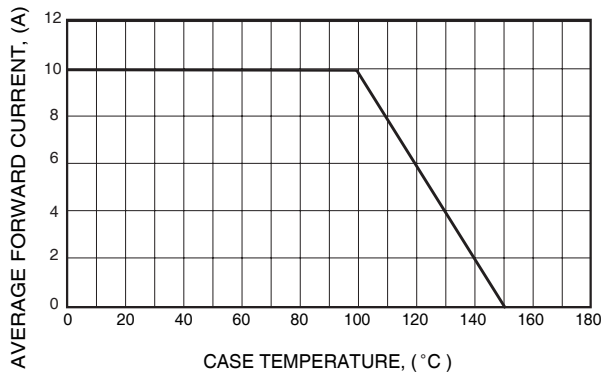


FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

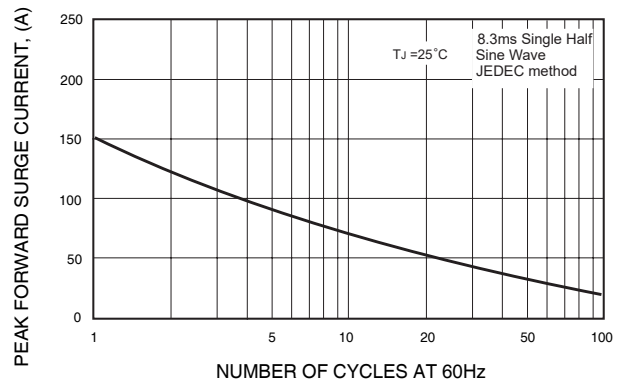


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

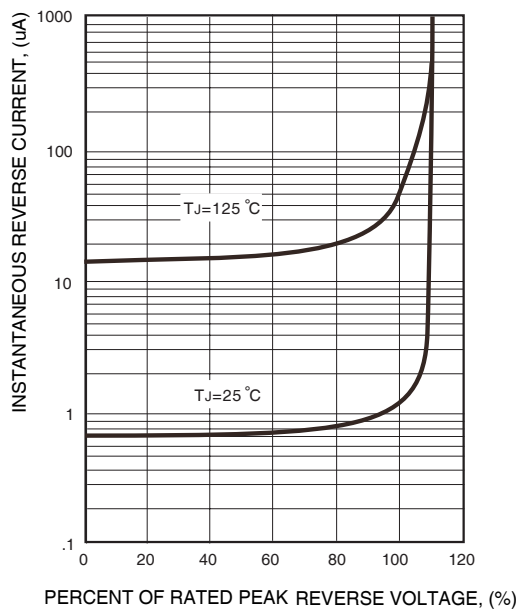


FIG. 2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

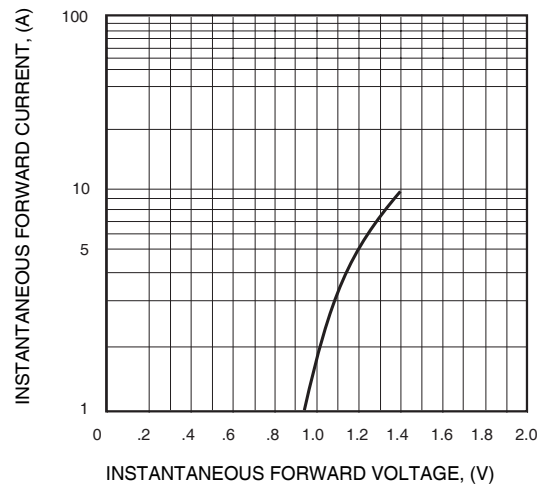
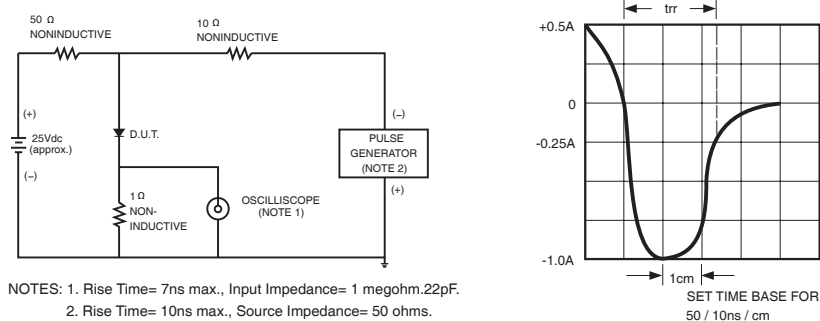


FIG.6- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



Package outline Dimensions in millimeters

